



Ultrafast Rectifier

15ETH03
15ETH03S
15ETH03-1

Features

- Ultrafast Recovery Time
- Low Forward Voltage Drop
- Low Leakage Current
- 175°C Operating Junction Temperature

$$t_{rr} = 40\text{ns}$$

$$I_{F(AV)} = 15\text{Amp}$$

$$V_R = 300\text{V}$$

Description/ Applications

International Rectifier's 300V series are the state of the art Ultrafast recovery rectifiers designed with optimized performance of forward voltage drop and Ultrafast recovery time.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in the output rectification stage of SMPS, UPS, DC-DC converters as well as freewheeling diodes in low voltage inverters and chopper motor drives.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

Absolute Maximum Ratings

Parameters	Max	Units
V_{RRM} Repetitive Peak Reverse Voltage	300	V
$I_{F(AV)}$ Average Rectified Forward Current @ $T_C = 142^\circ\text{C}$	15	A
I_{FSM} Non Repetitive Peak Surge Current @ $T_J = 25^\circ\text{C}$	140	
T_J, T_{STG} Operating Junction and Storage Temperatures	- 65 to 175	$^\circ\text{C}$

Case Styles

15ETH03	15ETH03S	15ETH03-1
		
TO-220AC	D ² PAK	TO-262

Electrical Characteristics @ T_J = 25°C (unless otherwise specified)

Parameters	Min	Typ	Max	Units	Test Conditions
V _{BR} , V _r Breakdown Voltage, Blocking Voltage	300	-	-	V	I _R = 100μA
V _F Forward Voltage	-	1.05	1.25	V	I _F = 15A, T _J = 25°C
	-	0.85	1.00	V	I _F = 15A, T _J = 125°C
I _R Reverse Leakage Current	-	0.05	40	μA	V _R = V _R Rated
	-	12	400	μA	T _J = 125°C, V _R = V _R Rated
C _T Junction Capacitance	-	45	-	pF	V _R = 300V
L _S Series Inductance	-	8	-	nH	Measured lead to lead 5mm from package body

Dynamic Recovery Characteristics @ T_J = 25°C (unless otherwise specified)

Parameters	Min	Typ	Max	Units	Test Conditions
t _{rr} Reverse Recovery Time	-	-	40	ns	I _F = 1.0A, di _F /dt = 50A/μs, V _R = 30V
	-	32	-		T _J = 25°C
	-	45	-		T _J = 125°C
I _{RRM} Peak Recovery Current	-	2.4	-	A	T _J = 25°C
	-	6.1	-		T _J = 125°C
Q _{rr} Reverse Recovery Charge	-	38	-	nC	T _J = 25°C
	-	137	-		T _J = 125°C

Thermal - Mechanical Characteristics

Parameters	Min	Typ	Max	Units
T _J Max. Junction Temperature Range	- 65	-	175	°C
T _{Stg} Max. Storage Temperature Range	- 65	-	175	
R _{thJC} Thermal Resistance, Junction to Case Per Leg	-	1.02	2.0	°C/W
R _{thJA} ① Thermal Resistance, Junction to Ambient Per Leg	-	-	70	
R _{thCS} ② Thermal Resistance, Case to Heatsink	-	0.2	-	
Wt Weight	-	2.0	-	g
	-	0.07	-	(oz)
Mounting Torque	6.0	-	12	Kg-cm
	5.0	-	10	lbf.in

① Typical Socket Mount

② Mounting Surface, Flat, Smooth and Greased

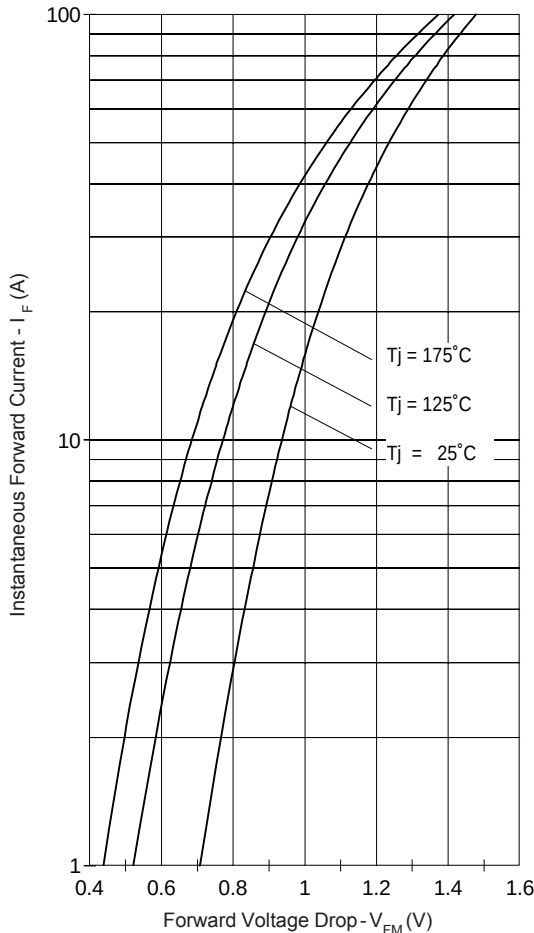


Fig. 1 - Typical Forward Voltage Drop Characteristics

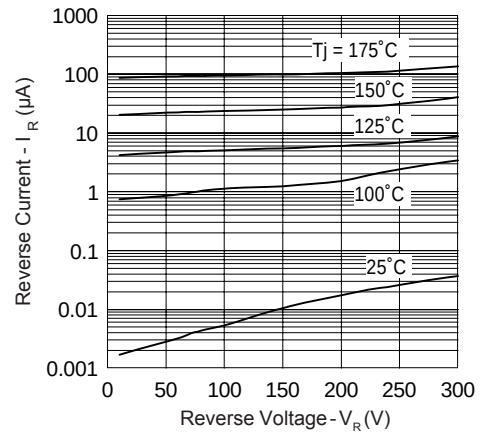


Fig. 2 - Typical Values Of Reverse Current Vs. Reverse Voltage

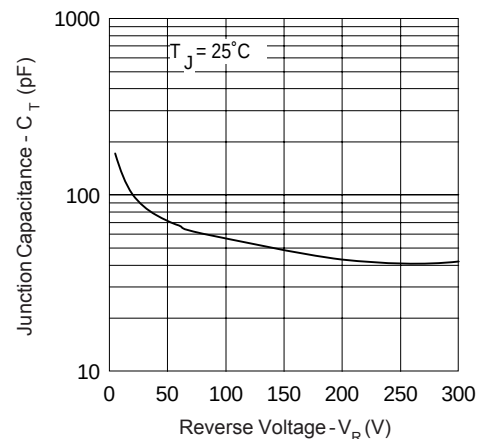


Fig. 3 - Typical Junction Capacitance Vs. Reverse Voltage

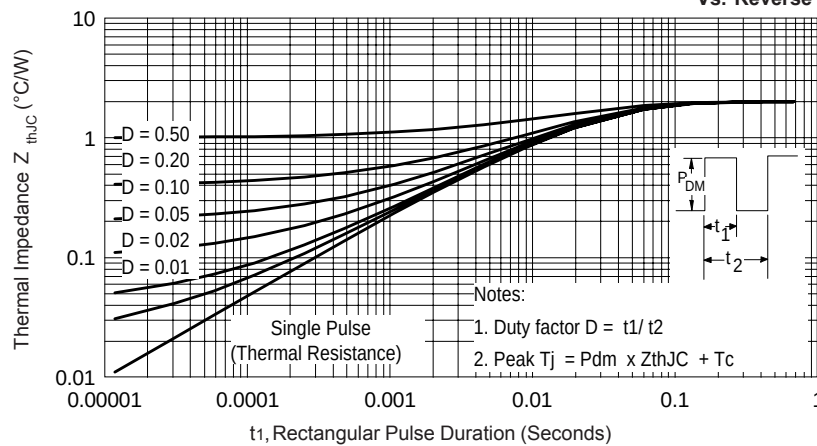


Fig. 4 - Max. Thermal Impedance Z_{thJC} Characteristics

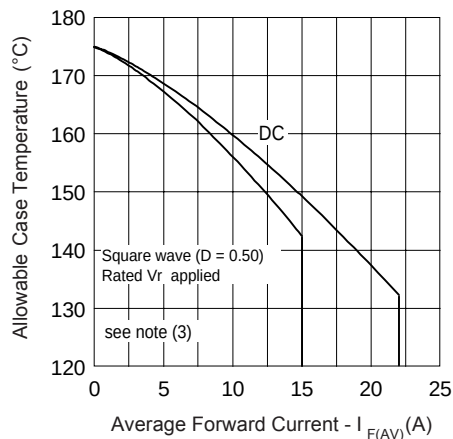


Fig. 5 - Max. Allowable Case Temperature Vs. Average Forward Current

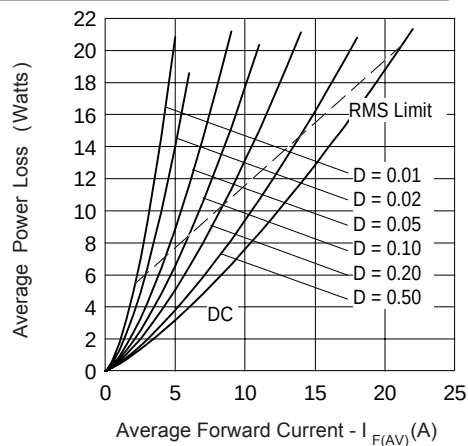


Fig. 6 - Forward Power Loss Characteristics

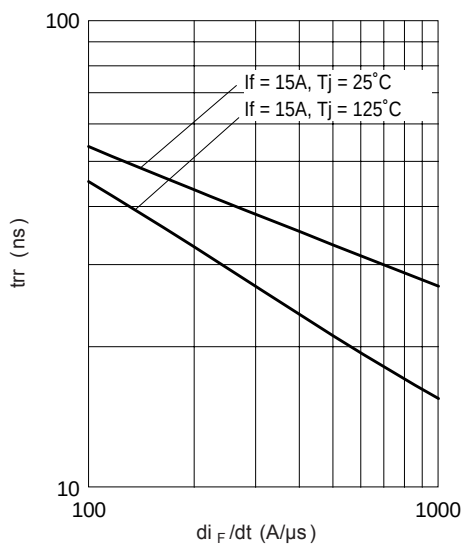


Fig. 7 - Typical Reverse Recovery vs. di_F/dt

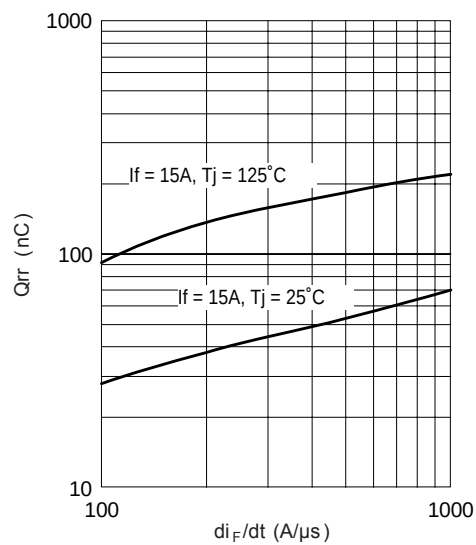


Fig. 8 - Typical Stored Charge vs. di_F/dt

(3) Formula used: $T_C = T_J - (P_d + P_{d_{REV}}) \times R_{thJC}$;

P_d = Forward Power Loss = $I_{F(AV)} \times V_{FM} @ (I_{F(AV)} / D)$ (see Fig. 6);

$P_{d_{REV}}$ = Inverse Power Loss = $V_{R1} \times I_R (1 - D)$; $I_R @ V_{R1}$ = rated V_R

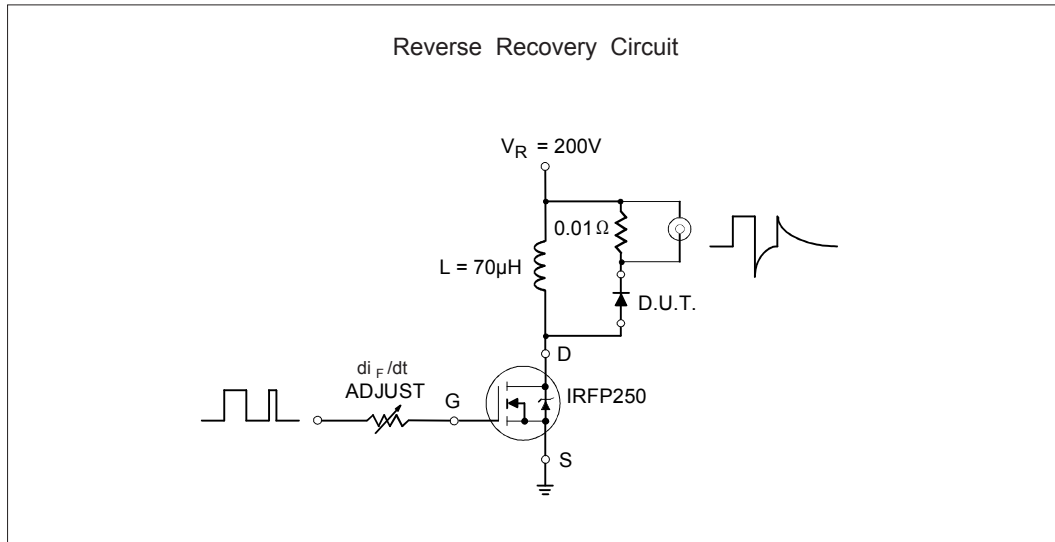


Fig. 9 - Reverse Recovery Parameter Test Circuit

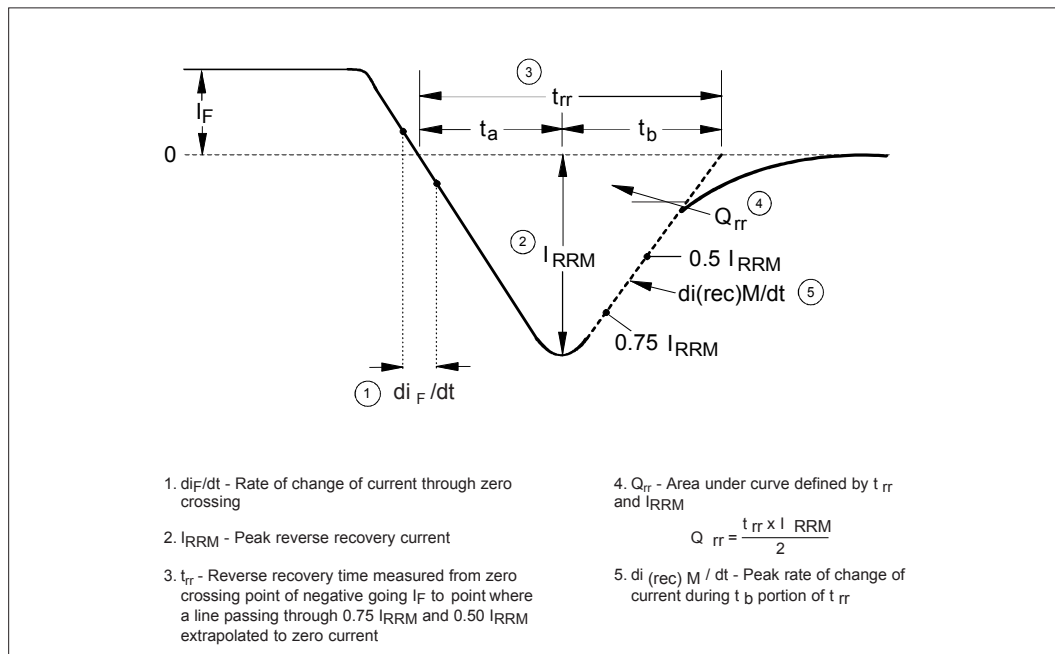
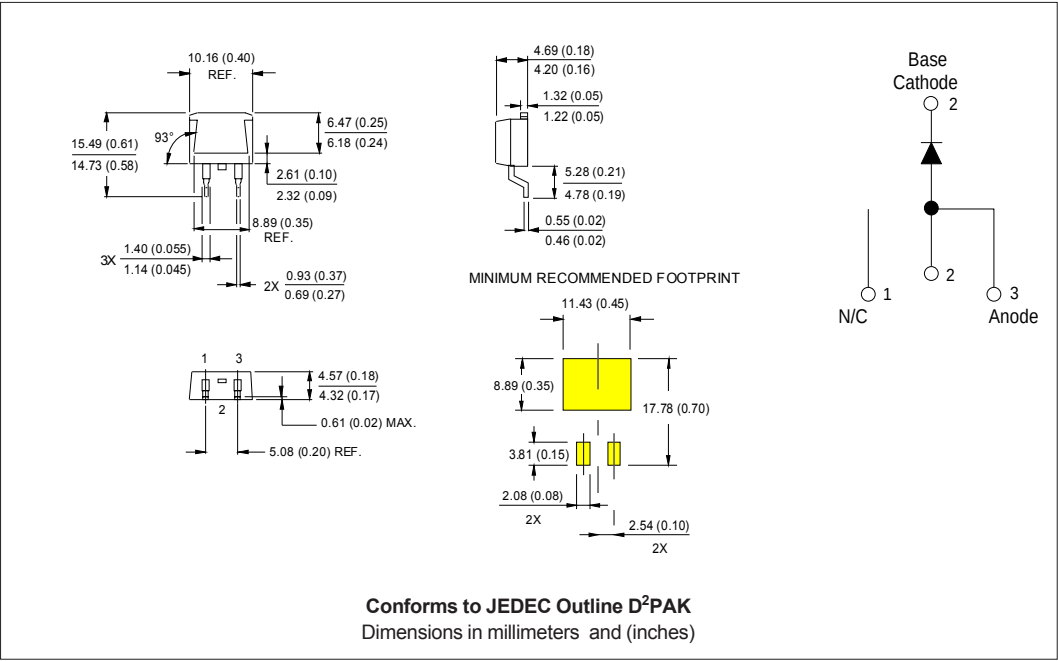
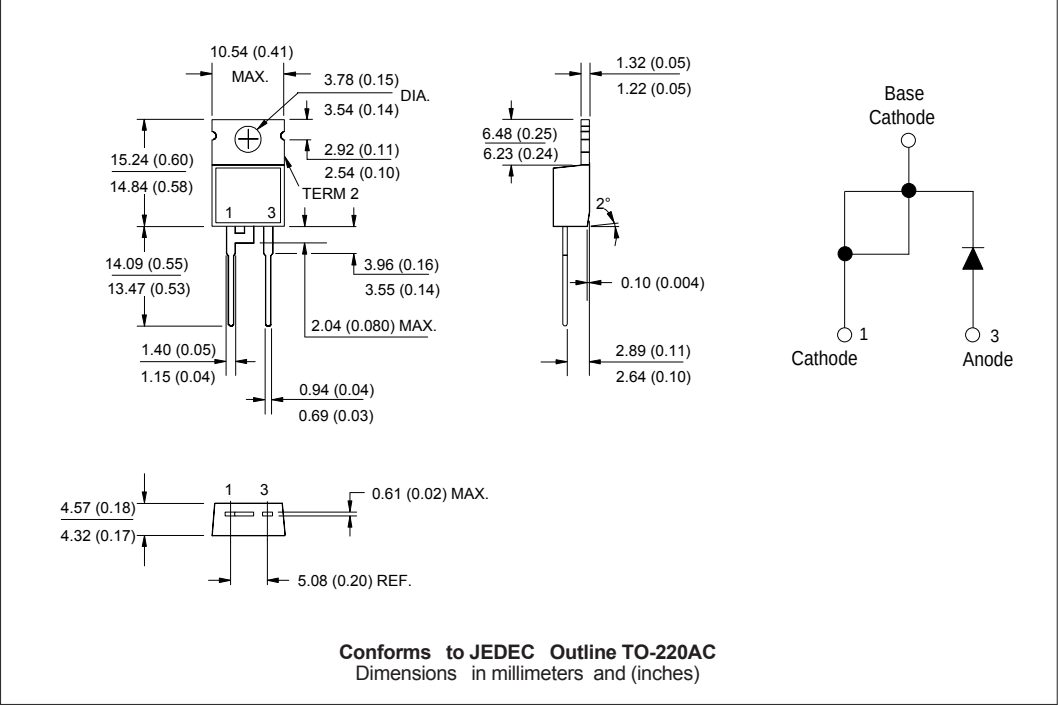
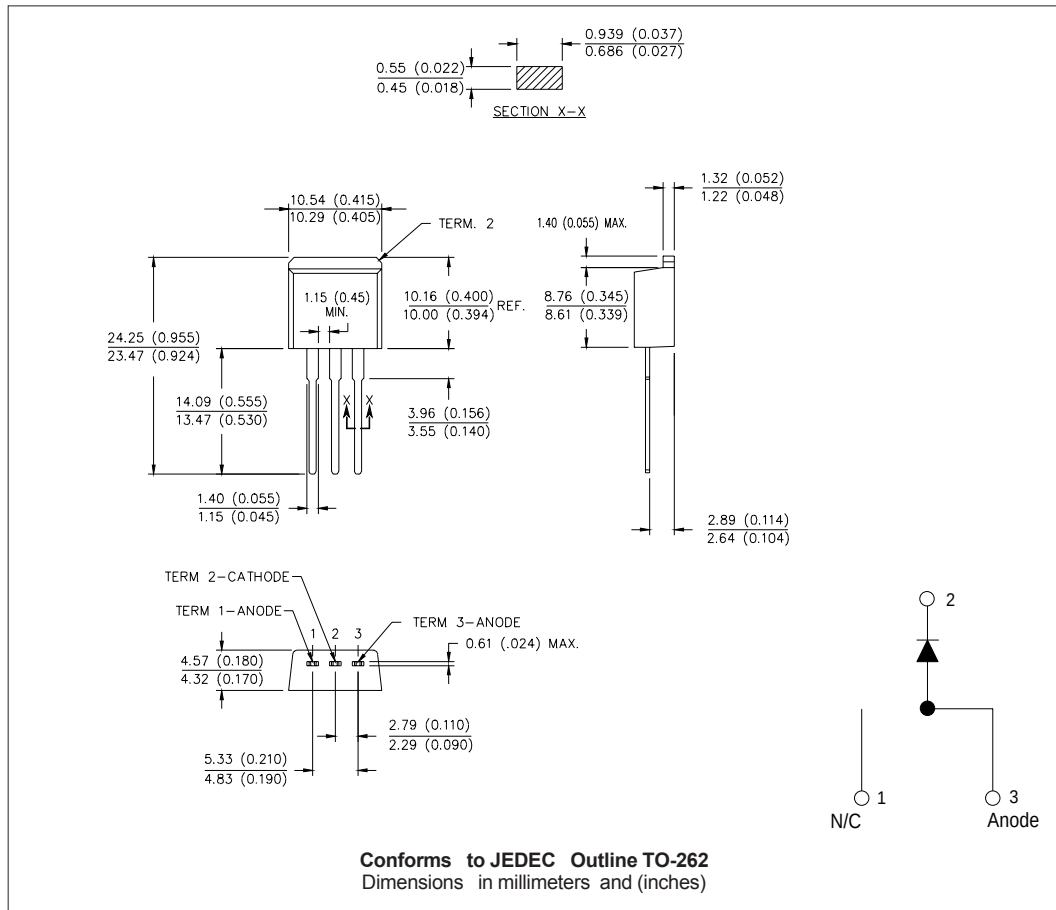


Fig. 10 - Reverse Recovery Waveform and Definitions

Outline Table

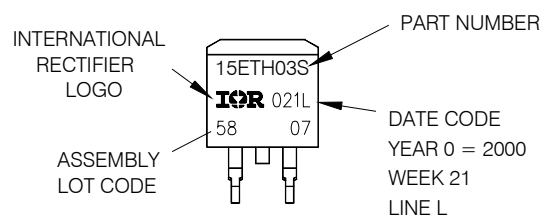


Outline Table



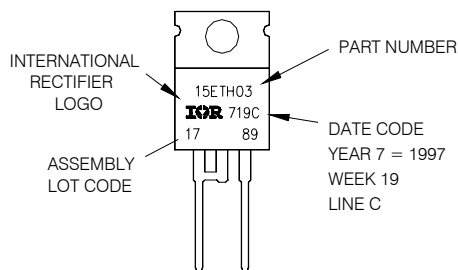
Marking Information

EXAMPLE: THIS IS A 15ETH03S WITH
LOT CODE 58 07
ASSEMBLED ON WW 21, 2000
IN THE ASSEMBLY LINE "L"



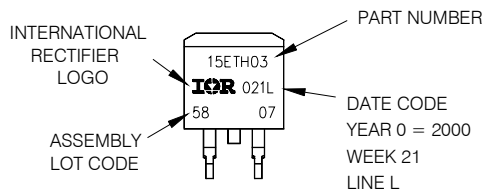
Part Marking Information

EXAMPLE: THIS IS A 15ETH03
LOT CODE 1789
ASSEMBLED ON WW 19, 1997
IN THE ASSEMBLY LINE "C"



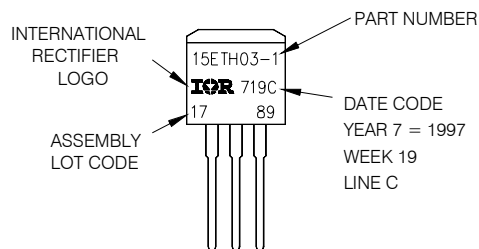
TO-220AC

EXAMPLE: THIS IS A 15ETH03S WITH
LOT CODE 58 07
ASSEMBLED ON WW 21, 2000
IN THE ASSEMBLY LINE "L"



D2Pak

EXAMPLE: THIS IS A 15ETH03-1
LOT CODE 1789
ASSEMBLED ON WW 19, 1997
IN THE ASSEMBLY LINE "C"



TO-262

Data and specifications subject to change without notice.
This product has been designed and qualified for Industrial Level.
Qualification Standards can be found on IR's Web site.

International
IR Rectifier

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